

UMX-599-D16-G

ULTRA-LOW NOISE COAXIAL RESONATOR OSCILLATOR

Package: D16, 12.7mm x 12.7mm x 5.59mm

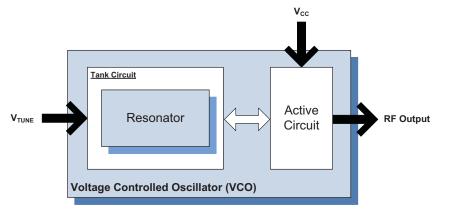


Features

- Ultra-linear Tuning/Ultra-low Phase Noise
- Frequency: 2100MHz to 2120MHz
- Resonator: Ceramic
- PCB: Rogers
- Package Size: 12.7mm x 12.7mm x 5.59mm (0.5in x 0.5in x 0.22in)

Applications

- Point-to-Point Radio
- DRO/YIG Multiplied Replacements
- Low Phase Noise Applications
- SAW VCO Replacements



Functional Block Diagram

Product Description

This VCO series features ultra-low phase noise, lower phase transients, lower harmonics, and lower pushing and pulling without any performance penalties typically associated with high technology designs.

Ordering Information

UMX-599-D16-G Contact us at 1-480-756-6070

Optimum Technology Matching® Applied

🗌 GaAs HBT	SiGe BiCMOS	🗌 GaAs pHEMT
GaAs MESFET	Si BiCMOS	□_Si CMOS
InGaP HBT	SiGe HBT	🗹 Si BJT

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GaN HEMT BiFET HBT LDMOS

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Absolute Maximum Ratings

0		
Parameter	Rating	Unit
Operating Ambient Temperature[1]	-40 to +85	°C
Storage Temperature	-55 to +125	°C

[1] Frequency drift: 3MHz typical, 4.5MHz maximum (either extreme)



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2002/95/EC.

Parameter		Specification		l lus it	
	Min.	Тур.	Max.	Unit	Condition
Overall					
Frequency Range	2100		2120	MHz	
Tuning Voltage	0.5		4.5	V _{DC}	
Tuning Sensitivity		9.5		MHz/V	
Output Power	5	7	9	dBm	
	4				At $V_T = 0$
Output Phase Noise		-95	-90	dBc/Hz	1kHz
		-120	-115	dBc/Hz	10kHz
		-140	-135	dBc/Hz	100kHz
		-160	-155	dBc/Hz	1000 kHz
		-164	-159	dBc/Hz	10000kHz
Second Harmonic		-12	-8	dBc	
Frequency Pulling		1	2	MHz p-p	At 12dBr, all phases
Tuning Port Capacitance		28		pF	
Modulation Bandwidth		1000		kHz	3dB BW
Frequency Pushing		0.2	0.5	MHz/V	
Power Supply	· · ·		·		
Operating Voltage		8		V	
Supply Current		29		mA	





Package Drawing & Pin Outs

12.7mm x 12.7mm x 5.59mm (0.5in x 0.5in x 0.22in)

